Semiconductor Science and Technology Volume 35, Issue 4, 19 March 2020, Article number 045029

## Theoretical studies of the generation of picoseconds pulses with two-section blue-violet semiconductor lasers

Tronciu, V. 1

Wenzel, H. 2

Knigge, A. 2

1 Department of Physics, Technical University of Moldova, bd. Stefan cel Mare 168, Chisinau MD-2004, Moldova

2 Ferdinand-Braun-Institut, Leibniz-Institut für Höchstfrequenztechnik, Gustav-Kirchhoff-Str. 4, D-12489 Berlin, Germany

**DOI** <a href="https://doi.org/10.1088/1361-6641/ab74f0">https://doi.org/10.1088/1361-6641/ab74f0</a>

## **Abstract**

We report the results of theoretical investigations of the generation of sub-10 ps pulses by a blue-violet InGaN two-section laser. The principle of pulse generation is active Q-switching. We study numerically the influence of the length of the switching section and the emission wavelength on the steady-state and dynamic behaviour. We investigate also the impact of the gain-compression factor on peak power, pulse energy and pulse width and compare the numerical results with semi-analytic expressions.